



Hall Effect Current Sensors L08P***D15W / IPV

Features:

- Open Loop type
- Printed circuit board mounting
- 4 pin PCB connection
- Bipolar power supply
- Extended measurement range
- Insulated plastic case according to UL94V0
- Advantages:
- Excellent accuracy
- Very good linearity
- Low temperature drift
- No insertion loss
- High Immunity To External Interference

 $T_A=25^{\circ}C$, $V_{CC}=\pm 15V$, $R_L=10k\Omega$

Current overload capability

Specifications

Parameters	Symbol	L08P100D15IPV	L08P200D15W	L08P300D15IPVW
Primary nominal current	l _f	100AT	200AT	300AT
Saturation current	I _{fmax}	≥ ±300AT	≥ ±600AT	≥ ±600AT
Rated output voltage	Vo	4V ±0.040V (at lf)		
Offset voltage ¹	V _{of}	≤ ± 0.030V (at If = 0A)		
Output linearity ² (0A~If)	٤∟	≤ ±1% (at lf)		
Power supply voltage	Vcc	±15V ± 5%		
Consumption current	lcc	≤ 20mA		
Response time ³	tr	≤ 5µs (at di/dt = 100A / µs)		
Thermal drift of gain ⁴	TcVo	≤ ± 0.05% /°C		
Thermal drift of offset	TcVof	≤ ± 1.0mV /°C		
Hysteresis error	V _{OH}	≤ 20mV (at If=0A→If→0A)		
Insulation voltage	V _d	AC 2500V for 1minute (sensing current 0.5mA), inside of through hole \Leftrightarrow terminal		
Insulation resistance	R _{IS}	≥ 500MΩ (at DC500V), inside of through hole \Leftrightarrow terminal		
Ambient operation temperature	T _A	-20°C ~ +80°C		
Ambient storage temperature	Τs	-25°C ~ +85°C		

¹ After removal of core hysteresis— ² Without offset —³ Time between 10% input current full scale and 90% of sensor output full scale — ⁴ Without Thermal drift of offset

Electrical Performances





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Mechanical dimensions





